Topological Cathodes:
Controlling the Space Charge Limit of Electron Emission Using Metamaterials
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Abstract
The space charge limit (SCL) of emission from photocathodes seriously limits the performance of both high- and low-field electron guns. In both cases, one is forced to strike a compromise between the space charge limit and the cathode’s intrinsic emittance (I. Bazarov et al. Phys. Rev. Lett., 102, 104801(2009)).

This work shows it is possible to not just mitigate the effects of the SCL, but to eliminate it by engineering the topography of the cathode’s surface. The concept is that a cathode with a surface plasma frequency below the frequency spectrum of the accelerating electrons will have zero-image charge and have no image-charge field. Therefore, the cathode has no space charge limit. The mathematical procedure for combining the cathode’s surface dielectric function with the beam dynamics is described. And the paper concludes with a SCL-free cathode design using a wire-array metasurface. This meta-cathode should have no space charge limit due to the image-charge field for both photo and thermionic emission.

I. Introduction

Eliminating the space charge image field at the cathode’s surface would automatically increase the cathode field by several MV/m for high charge beams without changing anything in the RF or HVDC system powering the gun. In addition, without the image field, the mean transverse energy (MTE) could be reduced by using a smaller laser spot without ever reaching the space charge limit (SCL) of emission. The smaller beam size would also reduce the chromatic and geometric aberrations in the injector’s optics. This paper shows it is possible to eliminate the cathode’s SCL by re-engineering the cathode’s electronic properties.

Because the image charge is determined by the dielectric function of the cathode’s surface, it is possible to design the surface to reduce and even eliminate the electron’s reflection by making the cathode ‘transparent’ at low frequencies. This transparency occurs if the surface’s plasma frequency is below the electron bunch’s frequency spectrum. In this case, the bunch’s spectrum will be in the region of ‘UV transparency’ and there is no image charge field and therefore no space-charge limit.

Of course, even without the image fields, there remains the space charge force between electrons inside the bunch. For these inter-beam space charge forces, there are established techniques of emittance compensation and laser shaping which can preserve both the transverse and longitudinal phase spaces. In addition, the method used to eliminate the SCL described in this paper can be extended to aid emittance preservation. However, these internal space charge forces are ignored in this work.

The space charge fields investigated here result from the electron’s attraction to its own image inside the cathode. Like an optical reflection, the image charge field is the reflection of the electron’s field by the cathode surface. In this work the ‘image charge’ method is used to obtain the image charge field of the bunch as the surface of the cathode. The image-charge field is evaluated at the bunch location and travels with the bunch as it accelerates from the cathode. In most instances the surface is highly reflective, thus the image charge is equal in magnitude but opposite in sign to the real charge. This is the case for all presently used cathodes, including semiconductor cathodes.

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This paper begins with a description of the image charge and its SCL. The relationship between the dielectric function and the surface response function, aka. the image-to-real charge ratio, is given and the conditions for controlling the SCL are described. A thin disk model of the beam which combines the time-dependence of the image-field with the surface response function is derived in Section III. In Section IV a meta-surface consisting of a rectangular array of vertical wires is used to illustrate the large range of dielectric properties a metamaterial can produce. The section also describes an optimized meta-surface and discussing the practical difficulties of using structured surfaces in high electric fields. Section V summaries the results and suggests directions for further research.

II. The image charge and the space charge limit of cathodes

There is no one space charge limit for an electron beam. There are several space charge limits which differ due to geometry of the electron beam and its interaction with the local environment. The best-known space charge limit (SCL) is the Child-Langmuir law which is specifically for a diode region with its gap filled with electrons [1]. There is also the SCL or limiting current which can be transmitted through a pipe with a given diameter [2]. And there are the SCLs of electron bunches which depend upon their transverse-to-longitudinal aspect ratio [3].

In high voltage RF and DC photocathode guns space charge limited emission occurs when the image charge field and the applied field are equal. The image charge is the `reflection' of the bunch itself inside the cathode surface. In the image method [4] an electron a short distance away from the cathode sees a mirror image of itself which is an equal distance inside the cathode. If the cathode has a dielectric constant larger than 1 then the image charge is opposite in polarity to the electron's charge, making the image charge field is attractive, pulling the electron back toward the cathode.

The image method gives the ratio of the image charge, \( q' \), to the real charge, \( q \), as

\[
\frac{q'}{q} = - \left( \frac{\varepsilon_c - 1}{\varepsilon_c + 1} \right)
\]  

(1)

Where \( \varepsilon_c \) is the cathode dielectric constant or relative electric permittivity defined in terms of the cathode's electric permittivity, \( \varepsilon_{\text{cathode}} \), and electric susceptibility, \( \chi_e \), as

\[
\varepsilon_{\text{cathode}} = \varepsilon_0 \varepsilon_c = \varepsilon_0 (1 + \chi_e)
\]  

(2)

The frequency dependent image charge is the negative of the surface loss function at low momentum transfer [5],

\[
g(q \to 0, \omega) = \left( \frac{\varepsilon(\omega) - 1}{\varepsilon(\omega) + 1} \right)
\]  

(3a)

And therefore, since \( q \sim 0 \) for photoemission, one can define the surface loss function for the cathode as

\[
g_c(\omega) \equiv \left( \frac{\varepsilon_c(\omega) - 1}{\varepsilon_c(\omega) + 1} \right)
\]  

(3b)

which makes the charge ratio equal to the negative of the surface loss function or \( q'/q = -g_c(\omega) \).

In this paper \( \varepsilon_c(\omega) \) will be called the dielectric function of the cathode. Because of this frequency-dependence, the SCL will also depend upon the cathode's surface loss function as well as the bunch's frequency spectrum and dimensions. This is described in the next section.

In the Drude theory [6] the dielectric function can be specified in terms of the material's plasma frequency and relaxation or collision time. The Drude dielectric function is given by

\[
\varepsilon(\omega) = 1 + \frac{\omega_p^2}{\omega(\omega + \tau_p)}
\]  

(4)

where the plasma frequency is given by, \( n \), the number density of conduction band electrons

\[
\omega_p^2 = \frac{4\pi ne^2}{\varepsilon_0 m}
\]  

(5a)
and the relaxation time, \( \tau_p \), depends upon the electrical conductivity, \( \sigma \),

\[
\tau_p = \frac{m \sigma}{ne^2}
\]  

(5b)

where \( m \) is the mass of an electron and \( e \) is its charge. Therefore, the dielectric properties of a cathode can be specified by just two physical properties: the density of the conduction electrons and the DC conductivity.

Table 1 shows the plasma frequency of copper \((10^{16} \text{ rad/sec})\) is four-orders of magnitude higher than the frequency spectrum of a 1 ps (~\(10^{12} \text{ rad/sec}\)) bunch. The same is true for the other commonly used cathode materials. Eqn. (4) indicates that when \( \omega_p \gg \omega \) then \( \left| \varepsilon \left( \omega_p \gg \omega \right) \right| \gg 1 \). In other words, when the bunch frequency spectrum is below the plasma frequency the magnitude of the dielectric function becomes large, and the image-charge to real-charge ratio goes to \(-1\). Thus, the image charge is equal in magnitude and opposite in sign to that of the real charge. All cathodes currently operate in this low frequency region below \( \omega_p \) where the dielectric constant is much greater than 1 and \( q'/q=-1 \).

**Table 1. Free electron properties of metals commonly used for cathodes.** The electron densities are taken from Table 1.1 and the relaxation times from Table 1.3 of Ref [6].

<table>
<thead>
<tr>
<th>Material</th>
<th>Copper</th>
<th>Cesium</th>
<th>Ga</th>
</tr>
</thead>
<tbody>
<tr>
<td>number density, ( n / \text{m}^3 )</td>
<td>8.47x10^{28}</td>
<td>9x10^{27} (5K)</td>
<td>1.54x10^{29}</td>
</tr>
<tr>
<td>relaxation time, ( \tau ) (sec)</td>
<td>2.7x10^{-14}</td>
<td>2.1x10^{-14}</td>
<td>1.7x10^{-15}</td>
</tr>
<tr>
<td>Plasma freq., ( \omega_p ) (rad/s)</td>
<td>1.64x10^{16}</td>
<td>5.3x10^{15}</td>
<td>2.2x10^{16}</td>
</tr>
<tr>
<td>DC conductivity (S/m)</td>
<td>6.3x10^{7}</td>
<td>5.3x10^{6}</td>
<td>7.3x10^{6}</td>
</tr>
<tr>
<td>Transition freq., ( \omega_t ) (rad/s)</td>
<td>1.16x10^{16}</td>
<td>3.8x10^{15}</td>
<td>1.6x10^{16}</td>
</tr>
</tbody>
</table>

The dielectric function given in Eqn. (4) is a complex function whose real and imaginary parts are plotted in Figure 1. The figure shows the imaginary part diverging at frequencies below the plasma frequency, whereas the real part becomes the DC conductivity at \( \omega = 0 \). And according to Eqns. (1) and (3), the image charge and the surface response function become zero when the dielectric function is equal to one. This happens at frequencies above the plasma frequency.

The ratio of the image charge to the real charge is shown in Figure 2. The calculations are based upon Eqn. (4) for the cathode dielectric function in terms of copper’s plasma frequency and relaxation time. Both the real and imaginary parts are divergent at a transition frequency where the real part switches from \(-1\) to \(0\), and the imaginary part is a narrow, negative peak and is zero everywhere else. This is the transition frequency where the cathode’s image charge switches from that of a metal (\( q'/q=-1 \)) to that of a vacuum with zero image charge (\( q'/q=0 \)). This effect is similar to the well-known phenomenon of ultraviolet transparency in metals [7]. In the present case, transparency occurs when the image charge takes on the charge of the vacuum, \( q'=0 \), and from the beam’s perspective the cathode ‘disappears’.

The transition from metal to vacuum occurs when the denominator in Eqn. (4) is zero, or when

\[
\varepsilon_c (\omega_t) = -1
\]  

(6)

where \( \omega_t \) is the transition frequency. Setting the real part of the Drude formula for \( \varepsilon_c \) equal to \(-1\),

\[
\text{Re} \left( 1 + i \frac{\omega_p^2 \tau_p}{\omega_t (1 - i \omega_t \tau_p)} \right) = -1
\]  

(7)

Solving for \( \omega_t \) gives

\[
\omega_t = \sqrt{\frac{\omega_p^2}{2} - \frac{1}{\tau_p^2}}
\]  

(8)
Notice that the transition frequency can be imaginary indicating the fields decay exponentially faster than a plasma period. This feature is used in the meta surface described in Section IVb where the transition frequency is imaginary. However, for most surfaces the plasma frequency term dominates, and the transition frequency becomes

\[ \omega_t \approx \frac{\omega_p}{\sqrt{2}} \]  

(9)

Which is similar to the relationship between the bulk and surface plasma frequencies.

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**Figure 1:** The complex dielectric function for copper at room temperature with different vertical and horizontal scales. The real part is plotted with the solid-red curves and the imaginary part is plotted using dash-blue curves. The plasma frequency is $1.64 \times 10^{16}$ rad/second and is the frequency where the real part is zero.

**Figure 2:** The image-charge to real-charge ratio as a function of frequency for copper. The dashed blue curve is the imaginary part and the solid red curve is the real part. A dash-dot line is drawn at -1 corresponding the charge ratio assumed in current cathode models. The transition frequency is $\omega_t = 1.16 \times 10^{16}$ radians/second.
Figure 2 clearly indicates that frequencies of the bunch current which are higher than the transition frequency have no image charge (the surface response function is zero) and therefore it follows that electron currents at these frequencies are not space charge limited. But utilizing this effect with existing cathodes to generate a beam requires emitting attosecond bunches from the cathode which is difficult. However, it is possible to instead change the cathode’s surface response function and greatly lower the transition frequency to the terahertz range and eliminate the SCL for ps bunches. A cathode with such a low transition frequency essentially removes the space charge limits for currently used electron bunch shapes. We prove this is possible by developing an analytic theory of the image-charge fields which includes the non-linear effects of the cathode’s dielectric properties. And use this theory with the novel properties of metamaterials to engineer a cathode with a THz transition frequency.

III. The image-charge fields in space, time and frequency

The analysis begins by deriving the image-charge electric field experienced by a disk of electrons while it’s accelerated from the cathode. The Fourier transform of this transient field is multiplied by the dielectric function to get the image-charge field as a function of frequency. Fourier transforming this product back to time gives the image-charge field at the disk center as a function of the disk’s time of travel from the cathode. This new image-charge field now includes the surface response function and the beam-cathode geometry and can be used in a second iteration of the beam dynamics.

a. Image-charge fields at the cathode surface

The method of images can be used to compute the image-charge field of a thin disk of uniform charge surface density. The derivation begins with the axial field of a solitary disk of charge as shown in Figure 3 which is then placed at the image charge location behind the cathode. The field from this ‘image disk’ then gives the field at the beam’s position on the vacuum side.

The potential energy surrounding a thin disk has been analyzed using a Legendre polynomial series [8]. This work gives the axial electric potential at point P the distance $z_p$ from the surface of a disk with radius $R$ and surface charge density $\Sigma_0$ as

$$ V_{disk}(z_p) = \frac{\Sigma_0}{2\varepsilon_0} \left( \sqrt{z_p^2 + R^2} - |z_p| \right) = \frac{Q_0}{2\pi\varepsilon_0 R^2} \left( \sqrt{z_p^2 + R^2} - |z_p| \right) $$

(10)

![Figure 3: Parameters of a thin disk of charge.](image)

The image method [4] places an image of the real charge at the symmetrical position on the inside of the cathode to calculate the field it produces on the outside the cathode. Figure 4 shows the image method’s configuration for a real-charge disk at $z=z_s$ and its image is at $-z_s$. When $z_s = 0$ the disk is at the
cathode surface. Placing the disk at the image charge location and applying Eqn. (10) gives the image’s potential energy at the center of the real-charge disk

\[ V_{\text{total}}(z_s) = -E_a z_s - \frac{Q_0}{\varepsilon_0 \pi R^2} \left( \frac{\varepsilon_c - 1}{\varepsilon_c + 1} \right) \left( \sqrt{\frac{z_s^2}{4} + \frac{R^2}{4}} - z_s \right) \]  

(11a)

The first term is the potential energy associated with a constant applied field.

This paper ignores the space charge forces of the real-bunch electrons on each other, that is the forces between electrons when the disk is far from the cathode. This self-energy is responsible for radial and longitudinal expansion as the beam accelerates from the cathode. Various researchers have noted that if this expansion is linear then it produces no emittance growth.

The image-charge potential energy plus the applied field potential are shown in Figure 5 for a 50-pC disk as a function of position from the cathode. The plots indicate that the local potential well disappears for \( R > 200 \) microns and the peak of the well is approximately 50 microns from the cathode when the applied field is 50 MV/m. It is also interesting to note that the potential is finite at \( z_s = 0 \) and is equal to

\[ V_{\text{image}}(z_s = 0) = -\frac{Q_0}{\varepsilon_0 \pi R^2} \left( \frac{\varepsilon_c - 1}{\varepsilon_c + 1} \right) \]  

(11b)

The maximum height of the potential well is the Schottky potential which is interesting to compute for a dielectric-like cathode. Taking the derivative of Eqn. (11a), setting it equal to zero and solving for \( z \) gives the barrier’s peak location, \( z_m \), from the cathode surface. This distance is

\[ z_m = \frac{R}{2} \frac{1 - \frac{E_a}{E_{\text{disk}}}}{\sqrt{1 - \left(1 - \frac{E_a}{E_{\text{disk}}}\right)^2}} \]  

(12)

where

\[ E_{\text{disk}} = \frac{Q_0}{\varepsilon_0 \pi R^2} \left( \frac{\varepsilon_c - 1}{\varepsilon_c + 1} \right) \]  

(13)

The potential well disappears when \( z_m = 0 \). Here the applied field, \( E_a \), equals the equivalent image charge field of the disk, \( E_{\text{disk}} \). The Schottky potential at the center of the disk is found by evaluating the potential at \( z_m \).
\[ V(z_m) = \phi_{\text{disk}} = \frac{R}{2} \frac{E_a}{e} \left( \frac{E_a - 2}{E_{\text{disk}}^2} \right) \]

Figure 5: The image-charge potential energy plus the applied potential energy (as given by Eqn. (11a)) for a 50-pC disk of charge as a function of its distance from the cathode. The dashed curves are the potential energies for disks with 50-, 100- and 200-micron radii. The potential of a 50 MV/m applied field is given by the solid-red curve.

Returning to our calculation of the image field, the potential energy of the image charge at the center of a disk with charge \( Q_0 \) a distance \( z_s \) from a cathode surface is

\[ V_{\text{image}}(z_s) = -\frac{Q_0}{\varepsilon_0 \pi R^2} \left( \frac{\varepsilon_c - 1}{\varepsilon_c + 1} \right) \left( \frac{z_s}{z_s^2 + R^2} - z_s \right) \]  

Taking its derivative with respect to \( z_s \), \( \vec{E} = -\nabla V \), gives us the image-charge’s electric field acting on the center of the disk,

\[ E_{\text{image}}(t) = \frac{Q_0}{\varepsilon_0 \pi R^2} \left( \frac{\varepsilon_c - 1}{\varepsilon_c + 1} \right) \left( \frac{z_s(t)}{z_s(t)^2 + R^2} - 1 \right) \]  

Assuming the disk’s center of motion is mostly due to acceleration in the applied field, then its relativistic equation of motion is

\[ Z_s(t) = \frac{1}{\gamma'} \left( \sqrt{(\gamma' c t)^2 + 1} - 1 \right) \]

Here \( \gamma' \equiv \frac{E_a}{m c^2} \) is the normalized applied field.

The mathematical procedure is to compute the Fourier transform of \( E_{\text{image}} \), multiply it with the cathode response function (aka. \( q'/q \)) and then transform the product back to the time-dependent field which now includes the cathode’s dynamics on the disk’s image-charge field. Unfortunately, inserting Eqn. (17) into Eqn. (16) and attempting to obtain closed expression for the Fourier transform is extremely difficult. Instead a very good approximation for Eqn. (16) is a gaussian function as shown next.

Fitting the width and amplitude of a gaussian to \( E_{\text{image}} \) gives the following useful formula,

\[ E_{\text{image}}^{\text{gaussian}}(t) = -\frac{Q_0}{\varepsilon_0 \pi R^2} \left( \frac{\varepsilon_c - 1}{\varepsilon_c + 1} \right) e^{-\frac{t^2}{2\sigma_t^2}} \]
The rms width of the gaussian is a function of the disk radius and the normalized applied field,

\[ \sigma^2 = \frac{(1 + \gamma R/\sqrt{2})^2 - 1}{2 \ln 2 \gamma^2 c^2} \]  

(19)

Figure 6 shows that \( E_{\text{image}}^{\text{gaussian}} \) closely matches \( E_{\text{image}} \) and can be used to compute the transform. Using Eqn. (18) has two principal advantages. This first is the Fourier transform of a gaussian is another gaussian. Which makes it trivial to move between time and frequency domains. The second involves using the exact expression for \( E_{\text{image}} \) requiring numerical integrating the function to obtain the transform. Unfortunately, numerical techniques are prone to produce oscillating transforms and the integration limits need to be carefully adjusted for the answer to converge. There are none of these issues if the gaussian function used.

![Figure 6: Comparison of the image field (solid-red) with a parameterized Gaussian function (dash-blue). The disk radius is 1 mm, \( E_a = 20 \text{ MV/m} \) and the cathode dielectric constant is 100. The field is given in units of the field per picocoulomb of negative charge. The insert shows the disk position from the cathode as a function of time.](image)

**b. Fourier transforms of the image-charge field**

The Fourier integral is used to obtain the frequency spectrum of the time-dependent field seen by the disk as it accelerates from the cathode. This spectrum is a source of changing fields which drives currents in the cathode to produce the image charge via the frequency response of the dielectric function.

Since the function \( E_{\text{image}}(t) \) is an even function in time then the cosine-representation for the Fourier transform is used [9]. In this paper the Fourier transform of a function is denoted by the script-type of that function. Hence the Fourier transform of the image field is given by

\[ E_{\text{image}}(\omega) = \frac{2}{\pi} \int_0^\infty E_{\text{image}}(t) \cos \omega t \, dt \]  

(20)

And its transformation back to the time-coordinate is
\[ E_{\text{image}}(t) = \int_0^\infty E_{\text{image}}(\omega) \cos \omega t \, d\omega \]  

(21)

\( E_{\text{image}}(\omega) \) is the frequency spectrum of the image-charge field seen by the disk as it accelerates from the cathode. Assuming the gaussian formulation given in Eqn. (18) for the image-charge field, the integral in Eqn. (21) is easily computed with the result

\[ E_{\text{image}}^{\text{gaussian}}(\omega) = -\sqrt{\frac{2}{\pi \varepsilon_0 \pi R^2}} \frac{Q_0}{\varepsilon_c(\omega)} \sigma_t \frac{1}{(1+1/\varepsilon_c)} e^{-\frac{\omega^2 \sigma_t^2}{2}} \]  

(22)

Equation (22) is the frequency spectrum of the image-charge field responding to the electrical impulse generated by the accelerating disk. Transforming this spectrum back to time gives

\[ E_{\text{image}}^{\text{gaussian}}(t) = -\sqrt{\frac{2}{\pi \varepsilon_0 \pi R^2}} \frac{Q_0}{\varepsilon_c(\omega)} \sigma_t \int_0^\infty \frac{1}{(1+1/\varepsilon_c)} e^{-\frac{\omega^2 \sigma_t^2}{2}} \cos \omega t \, d\omega \]  

(23)

Using Drude’s theory for the dielectric function (see Eqn. (4)), this expression can be written in terms of the plasma frequency and the decay time of the cathode surface,

\[ E_{\text{image}}^{\text{gaussian}}(t) = -\sqrt{\frac{2}{\pi \varepsilon_0 \pi R^2}} \frac{Q_0}{\varepsilon_c(\omega)} \sigma_t \int_0^\infty \left( \frac{\omega_p^2}{\omega_p^2 - 2\omega(\omega + \frac{1}{\tau_p})} \right) e^{-\frac{\omega^2 \sigma_t^2}{2}} \cos \omega t \, d\omega \]  

(24)

A cathode surface with the high plasma frequency of most metals, then \( \varepsilon_c \gg 1 \), the image charge is a constant in frequency and the Fourier transform of \( E_{\text{image}}^{\text{gaussian}}(\omega) \) returns the original image field, \( E_{\text{image}}(t) = E_{\text{image}}(t) \). This is not a very interesting result. However, if one instead uses a frequency-dependent dielectric function with a transition frequency low enough to interact with the image charge spectrum then some interesting effects can be discovered as described next.

**IV. The dielectric function of a metasurface**

A metasurface is a surface composed of a pattern of structures each of which is smaller than the wavelength of the radiation of interest. In a metasurface each of these structures can be like an ‘atom’ forming a new ‘atomic’ structure of the surface. This pattern of structures can be arranged to produce a wide range of electrical and magnetic properties which are otherwise unobtainable in nature. In the case of cathode design, an important surface property is the dielectric function which affects the electron dynamics via the image charge. And as discussed earlier, a cathode with a low transition frequency will remove the cathode’s space charge limit.

This section consists of two parts. The first describes a metasurface whose transition frequency can be adjusted to study image charge electric field of the disk as a function of travel time from the cathode. The second discusses an optimized meta-cathode design.
a. Image-charge field as a function of the transition frequency

An example of a metasurface is a rectangular array of vertical, metallic wires standing perpendicular to the cathode surface [10]. Such an array has a plasma frequency given by

\[ \omega_{\text{wire}}^2 = \frac{2\pi c^2}{a^2 \ln \frac{a}{r}} \]  

(25)

and the relaxation time is

\[ \tau_{\text{wire}} = \frac{r^2 \sigma_{\text{wire}}}{2 \epsilon_0 c^2} \ln \frac{a}{r} \]  

(26)

Here \( a \) is the center-to-center distance between the wire, \( r \) is the wire radius, and \( c \) is the speed of light. The conductivity of each wire is \( \sigma_{\text{wire}} \), and \( \epsilon_0 \) is the permittivity of the vacuum between the wires.

By varying the three parameters: \( a \), \( r \) and \( \sigma_{\text{wire}} \), one can explore \( q'/q \) over a wide range of surface plasma frequencies and relaxation times. The dependence of the transition frequency and relaxation time upon the array parameters are shown in Table 3. The three cases of high, medium and low transition frequencies with respect to the spectrum of the accelerating disk are investigated by varying the wire spacing only. The wire radius is fixed at 10 microns and the conductivity is set to 1/100 that of copper. Wire spacings of 0.1-, 1- and 10-mm result in transition frequencies from the THz to GHz range. Whereas the relaxation time changes a factor of three.

Figure 7 shows the field vs. time, and the field and \( q'/q \) spectra for the three cases given in Table 3. The top row plots compare fields of the usual image-charge to real-charge ratio of -1 and the meta-surface image charge fields for wire spacings of 0.1, 1 and 10 mm. The bottom row shows the frequency spectra of the accelerating disk, and the real and imaginary parts of the image-to-real charge ratio for the three cases. The leftmost plots (\( a=0.1 \) mm) show the usual operating situation for current cathodes where the transition frequency is above the electron bunch spectrum.

The center plots in Figure 7 (\( a=1 \) mm) show the transition frequency overlapping the high frequency edge of the disk’s spectrum. In this case the image-charge field is reduced approximately a factor of two when the disk is close to the cathode (t<10ps). However, further from the cathode (t>10ps) the field begins oscillating while chirping to higher frequencies as the field decays to zero. While possibly detrimental to the beam quality, for some applications the oscillating image-charge field could be used to energy-modulate and pre-bunch the electrons.

And finally, the rightmost plots of Figure 7 (\( a=10 \) mm) show \( \omega_t \) at the low end of disk’s frequency spectrum. In this case the surface response function produces a negligible image-charge field with only small oscillations when the disk more than 10 ps from the cathode.

Table 3. Parameters for rectangular array of vertical wires. The wire conductivity is 1/100 that of copper.

<table>
<thead>
<tr>
<th>Parameter</th>
<th>0.1</th>
<th>1</th>
<th>10</th>
</tr>
</thead>
<tbody>
<tr>
<td>wire spacing, a (mm)</td>
<td>0.1</td>
<td>1</td>
<td>10</td>
</tr>
<tr>
<td>wire radius, r (microns)</td>
<td>10</td>
<td>10</td>
<td>10</td>
</tr>
<tr>
<td>wire conductivity, ( \sigma_{\text{wire}} )</td>
<td>6.3x10^5</td>
<td>6.3x10^5</td>
<td>6.3x10^5</td>
</tr>
<tr>
<td>relaxation time, ( \tau_{\text{wire}} ) (sec)</td>
<td>9.1x10^{-11}</td>
<td>1.8x10^{-10}</td>
<td>2.7x10^{-10}</td>
</tr>
<tr>
<td>array plasma freq., ( \omega_{\text{wire}} ) (radians/sec)</td>
<td>4.9x10^{12}</td>
<td>3.5x10^{11}</td>
<td>2.9x10^{10}</td>
</tr>
<tr>
<td>transition frequency, ( \omega_t ) (radians/sec)</td>
<td>3.5x10^{12}</td>
<td>2.5x10^{11}</td>
<td>2.0x10^{10}</td>
</tr>
</tbody>
</table>
Figure 7: (Top row) The image-charge field at the disk center vs. the disk’s time of travel from the cathode. The dash-blue curves are $E_{\text{image}}^{\text{gaussian}}(t)$, the usual image-charge field of a cathode with $|\varepsilon_c| \gg 1$. The red curves are $E_{\text{image}}^{\text{gaussian}}(t)$, the image-charge fields for wire arrays with spacings of 0.1, 1 and 10 mm. The other parameters given in Table 3. (Bottom row) The red curves are $E_{\text{image}}^{\text{gaussian}}(\omega)$, the frequency spectra of the disk normalized to 1 or $e^{-\omega^2 \sigma^2 / 2}$. The solid-blue curves are the real part of the image-to-real charge ratio, $-\Re \left( \frac{\epsilon_{c}(\omega)-1}{\epsilon_{c}(\omega)+1} \right)$ and the dash-magenta curves are the imaginary part, $-\Im \left( \frac{\epsilon_{c}(\omega)-1}{\epsilon_{c}(\omega)+1} \right)$.

The disk radius is $R=1$ mm and the normalized applied field is $\gamma' = 39 / m$.

b. An optimized meta-surface and practical considerations

The last sub-section showed that it is possible to eliminate the image-charge SCL with an array of vertical wires. However, this was accomplished using a very coarse wire spacing of 10 mm. This large spacing leads to an impractically large cathode area because the array pattern should extend over several wire spacings or periods. In this sub-section the meta-cathode’s radius is estimated from the disk-cathode geometry and the wire length estimated from the relaxation time.

The time it takes a signal to travel from center to edge of cathode and back to disk should be longer than the time it takes the disk to move far enough from the cathode to where the image-charge field is negligible. That way the disk is too far from the cathode for it can know when the speed of light signal returns from the cathode’s radial edge. Figure 6 and its insert show the image-charge field becomes zero when the disk is 40 ps from the cathode. Assuming the signal velocity is $c$, then the round-trip distance needs to be longer than the distance light travels in 40 ps, or $ct=12 \text{ mm}$. Hence,

$$R_{\text{cathode}} + \sqrt{R_{\text{cathode}}^2 + 3^2} > 12 \text{ mm}$$

Therefore, $R_{\text{cathode}} > 6 \text{ mm}$. 

11
The length of the wires can be estimated from the relaxation time. Although the model assumes the wires are isolated, this condition is clearly violated since one end is electrically connected to the cathode surface. However, the assumption can be made valid again provided the wires are long enough that a signal sent from the free end decays before reaching the attached end. Since the fastest any signal can travel is the speed of light, the wire needs to be longer than \( c \tau_{\text{wire}} \). If we want a wire length of 10 microns, then \( c \tau_{\text{wire}} \leq 10 \) microns and \( \tau_{\text{wire}} \leq 3 \times 10^{-14} \) seconds.

And finally, the conductivity of the wires should be low enough to damp the rapid oscillations when the transition frequency is close to the high frequency part of the disk’s frequency spectrum. Figure 7 indicates that a wire conductivity which is 1% that of copper still leads to strong oscillations when \( a=1 \) mm.

Using the above relations for the wire array properties, the wire radius, spacing and conductivity can be varied to find a solution which satisfies all these requirements. Table 4 lists the array parameters for one such solution. It is notable that the transition frequency is imaginary indicating the fields exponentially decay as they propagate into the surface. This because of the very short relaxation time of \( 3 \times 10^{-15} \) seconds which suggests a wire length of 1 micron (\( c\tau_{\text{wire}} = 1 \) micron).

Figure 10 shows the real and imaginary parts of the Fourier transformed image-charge electric field (top) and the image-bunch charge ratio (bottom) as functions of frequency (top), and the reconstructed image-charge electric field, \( E_{\text{image}}(t) \). The low conductivity of the wires damps the oscillations with essentially no image-charge field as shown by the red curve in the upper plot of Fig. 10.
Table 4. Parameters for rectangular array of vertical wires.
The wire conductivity is 1/1000 that of copper. These values are used to compute the curves in Fig. 10.

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>wire spacing, a (mm)</td>
<td>0.2</td>
</tr>
<tr>
<td>wire radius, r (microns)</td>
<td>0.1</td>
</tr>
<tr>
<td>wire conductivity, $\sigma_{wire}$ (S/m)</td>
<td>6.3x10^4</td>
</tr>
<tr>
<td>relaxation time, $\tau_{wire}$ (sec)</td>
<td>3.0x10^-15</td>
</tr>
<tr>
<td>wire length, $c\tau_{wire}$ (microns)</td>
<td>1</td>
</tr>
<tr>
<td>array plasma freq., $\omega_{wire}$ (radians/sec)</td>
<td>1.4x10^12</td>
</tr>
<tr>
<td>transition frequency, $\omega_t$ (radians/sec)</td>
<td>3.3i x10^{14}</td>
</tr>
</tbody>
</table>

Figure 10: Top: The image-charge electric field at the disk center as a function of the disk’s time of travel. The dash-blue curve is the field with $q'/q=-1$ and the solid-red curve is the field with an array of wires with the parameters given in Table 3. Bottom: The frequency spectrum of the accelerating disk is shown with a solid-red curve. The real (solid-blue) and imaginary (dash-magenta) $q'/q$ as a function of frequency or the negative of the surface response function, $\frac{q'}{q} = -g_c(\omega)$. The disk radius is $R=1$ mm and the normalized applied field is $\gamma' = 39$/m.

Figure 10 also illustrates some interesting features of the meta-surface. First is the surface response function (-$q'/q$) becomes -1 below approximately GHz. Thus, at low RF frequencies the surface behaves like a metal. This is because RF at long wavelengths cannot resolve the wires and to it the surface appears as a uniform metallic surface, albeit with a poor conductivity. However, normal to the surface the
conductivity is low only over the length of the wires. Low frequencies only ‘see’ the surface below the wire array where the conductivity is 1000-times better. Because the RF extends further into the cathode than the length of the wires and into the conductor below, the effective conductivity will be nearly that of the underlying conductor and the RF losses will be much less.

This can be shown by computing the RF skin depth \[\delta\] as given by

\[
\delta = \frac{2}{\sqrt{\mu_c \omega \sigma}}
\]

Here the RF frequency is \(\omega\), the conductor’s permeability is \(\mu_c\) and its conductivity is \(\sigma\). As an example, assume the LCLS-II RF gun frequency of 186 MHz. Using the 6.3x10^4 S/m conductivity of the wire array given in Table 3 results in a skin depth of 147 microns. Thus, the RF passes through the 1-micron tall wire array with little dissipation and most of the power is deposited in the highly conductivity metal below.

Another possible heat source is the current of the beam itself as it is drawn from the surface. Here the heating can be mitigated by designing the emission area to be between the wires, and not from the wires themselves. Since the wire spacing is 200 microns, a small region of four or five wires could be removed and replaced with a ~1mm diameter cathode. The effect this ‘defect’ has on the overall dielectric function can be compensated for by modifying the nearby array parameters. In cathodes using field emission from an array of points, needles or other high-aspect shapes, individual low conductivity wires can be replaced by one or more emission points.

An important issue is the electrical breakdown of the meta-surface with a high applied field. This phenomenon is a serious technical problem since the lower conductivity wires could be sources of high dissipative losses and in fact burnup if they draw too much current. This can happen during a high-field arcing and RF processing. Another concern is multipacting which may occur between the wires and other surfaces. These and other effects require further theoretical and experimental study. In addition, other meta-surface designs with lower profiles such as split-ring resonators should be investigated.

V. Summary and Discussion

This paper discussed the role of the cathode’s dielectric constant in the space charge limit of cathodes for use in electron guns. It began by showing the SCL is related to the image charge which is a function of the frequency-dependence of the dielectric constant or the dielectric function. Here the major point of the paper is stated, i.e. that lowering the transition frequency of the surface response function to below the frequencies of the electron bunch spectrum has a weak or even zero image charge field on the bunch. If the image-charge is zero, then there is no SCL. In addition, it is shown the dielectric function can be modified by applying the new concepts of topological surfaces and meta-materials. These new materials enable one to custom design any desired dielectric function and thereby control the image-charge forces.

The first half of the paper develops the image-charge field theory modelling a thin disk of uniform surface charge being accelerated from rest by a constant applied field. The theory gives the image charge field seen by the disk. The shape of this field is nearly independent of the bunch length and is determined by the distance the image-charge field extends from the surface and the time it takes the electrons to traverse it. The theory illustrates that the field’s spectrum can excite oscillations in the surface response function \(g(\omega) = -q'/q\). The oscillations are especially strong when the transition frequency overlaps the bunch’s spectrum.

Theory shows that for a thin disk of charge, the distance the image-charge field extends from the surface is determined by geometry and kinematics. The geometry is the transverse radius of the disk and
the kinematics is the acceleration by the applied field. This suggests that the frequency spectrum of a short duration of the electron bunch/pulse is not what drives with the cathode surface. Instead it is the spectrum produced by the combination of the image-charge field’s shape and the time it takes to accelerate the electrons across this field. This strongly implies that the same concept can be used to control the SCL of DC and long pulse beams.

The second half of the paper described the electronic behavior of a meta-surface consisting of a rectangular array of vertical wires. Varying the array parameters allowed control of the transition frequency over two decades and clearly demonstrated the proposed method of SCL elimination. Acceptable ranges for the wire parameters of wire diameter, spacing and length were established and used to optimize the design.

The paper ends with a discussion of the problems and issues hindering the use of meta-surfaces in high field guns. RF heating of the structured surface is not considered to be a problem because the RF skin depth of the meta-surface at frequencies below ~1GHz is larger then the thickness of the meta-surface. However, there is concern of breakdown and arcing when the surface is in a high electric field. Other meta-surface designs with lower profiles (lower enhancement factors) should be studied. A theory of electrical breakdown and multipacting for such small structures could be developed along with techniques for mitigating the problem.

This work opens new possibilities for electron source research with direct applications in accelerator physics. The wire array discussed in this paper demonstrates the concept of space charge control by custom engineering of the cathode’s dielectric function. Other more sophisticated meta-structures like split ring resonators should also be investigated for the ‘atoms’ of the array. Further research should explore using topological surfaces to control electron emission in both RF and DC guns with both photoelectric and thermionic cathodes.

Acknowledgements
I wish to thank my wife, Alice Pitt, for her support and patience. No DOE funds were spent on this work.

References